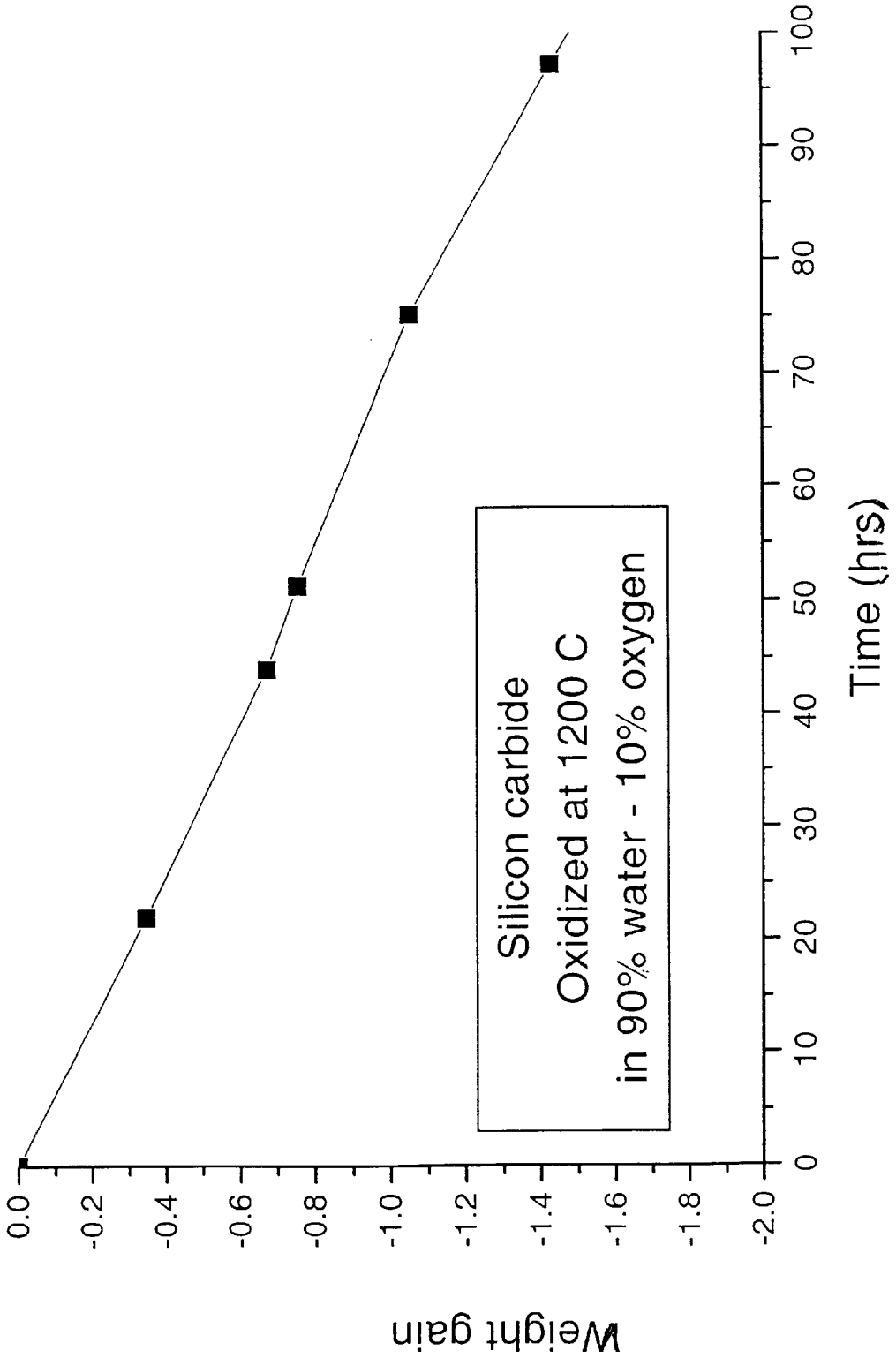
Silicon carbide
Oxidized at 1200 C
in 90% water - 10% oxygen
Weight gain
0.0
-0.2
-0.4
-0.6
-0.8
-1.0
-1.2
-1.4
-1.6
-1.8
-2.0
Time (hrs)
0
10
20
30
40
50
60
70
80
90
100

Figure 1